



FDH400/FDLL400
FDH444/FDLL444

High Voltage General Purpose Diodes

T-01-09

- BV... 200 V (MIN) FDH400
... 150 V (MIN) FDH444
- V_F... 1.1 V (MAX) @ 300 mA FDH400
@ 200 mA FDH444

PACKAGES

FDH400	DO-35
FDH444	DO-35
FDLL400	LL-34
FDLL444	LL-34

ABSOLUTE MAXIMUM RATINGS (Note 1)

Temperatures

Storage Temperature Range	-65°C to +200°C
Max Junction Operating Temperature	+175°C
Lead Temperature	+260°C

If you need this device in the SOT package, an electrical equivalent is available. See FDSO1400 family.

Power Dissipation (Note 2)

Maximum Total Dissipation at 25°C Ambient	500 mW
Linear Derating Factor (from 25°C)	3.33 mW/°C

Maximum Voltage and Currents

		FDH400	FDH444
WIV	Working Inverse Voltage	175 V	125 V
I _O	Average Rectified Current	200 mA	200 mA
I _F	Forward Current Steady State	500 mA	500 mA
I _F	Recurrent Peak Forward Current	600 mA	600 mA
I _F (surge)	Peak Forward Surge Current		
	Pulse width = 1.0 s	1.0 A	1.0 A
	Pulse width = 1.0 μs	4.0 A	4.0 A

ELECTRICAL CHARACTERISTICS (25°C Ambient Temperature unless otherwise noted)

SYMBOL	CHARACTERISTIC	FDH400		FDH444		UNITS	TEST CONDITIONS
		MIN	MAX	MIN	MAX		
VF	Forward Voltage		1.1		1.2	V	I _F = 300 mA
			1.0		1.1	V	I _F = 200 mA
BV	Breakdown Voltage	200		150		V	I _R = 100 μA
I _R	Reverse Current		100		50	nA	V _R = 150 V
			100		100	nA	V _R = 100 V
						μA	V _R = 150 V, T _A = 150°C
						μA	V _R = 100 V, T _A = 150°C
C	Capacitance		2.0		2.5	pF	V _R = 0, f = 1.0 MHz
t _{rr}	Reverse Recovery Time		50		60	ns	I _F = 30 mA, I _R = 30 mA R _L = 100 Ω, I _{rr} = 3.0 mA

NOTES:

1. The maximum ratings are limiting values above which life or satisfactory performance may be impaired.
2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
3. For product family characteristic curves, refer to Chapter 4, D1.

3